



BCM857QAS

45 V, 100 mA PNP/PNP matched double transistors

24 April 2018

Product data sheet

1. General description

PNP/PNP matched double transistors in an ultra small DFN1010B-6 (SOT1216) leadless Surface-Mounted Device (SMD) plastic package.

NPN/NPN complement: BCM847QAS

2. Features and benefits

- Reduces component count
- Reduces pick and place costs
- Low package height of 0.37 mm
- Current gain matching
- Base-emitter voltage matching
- Application-optimized pinout
- AEC-Q101 qualified

3. Applications

- Current mirror
- Differential amplifier

4. Quick reference data

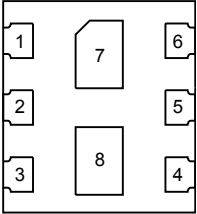
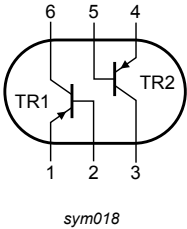
Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Per transistor						
V_{CEO}	collector-emitter voltage	open base	-	-	-45	V
I_C	collector current		-	-	-100	mA
I_{CM}	peak collector current	$t_p \leq 1$ ms; single pulse	-	-	-200	mA
h_{FE}	DC current gain	$V_{CE} = -5$ V; $I_C = -2$ mA; $T_{amb} = 25$ °C	200	290	450	
Per device						
h_{FE1}/h_{FE2}	DC current gain matching	$V_{CE} = -5$ V; $I_C = -2$ mA; $T_{amb} = 25$ °C	0.95	1	1.05	
$V_{BE1}-V_{BE2}$	base-emitter voltage matching		[1]	-	2	mV

[1] The smaller of the two values is subtracted from the larger value.

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	E1	emitter TR1	 Transparent top view DFN1010B-6 (SOT1216)	 sym018
2	B1	base TR1		
3	C2	collector TR2		
4	E2	emitter TR2		
5	B2	base TR2		
6	C1	collector TR1		
7	C1	collector TR1		
8	C2	collector TR2		

6. Ordering information

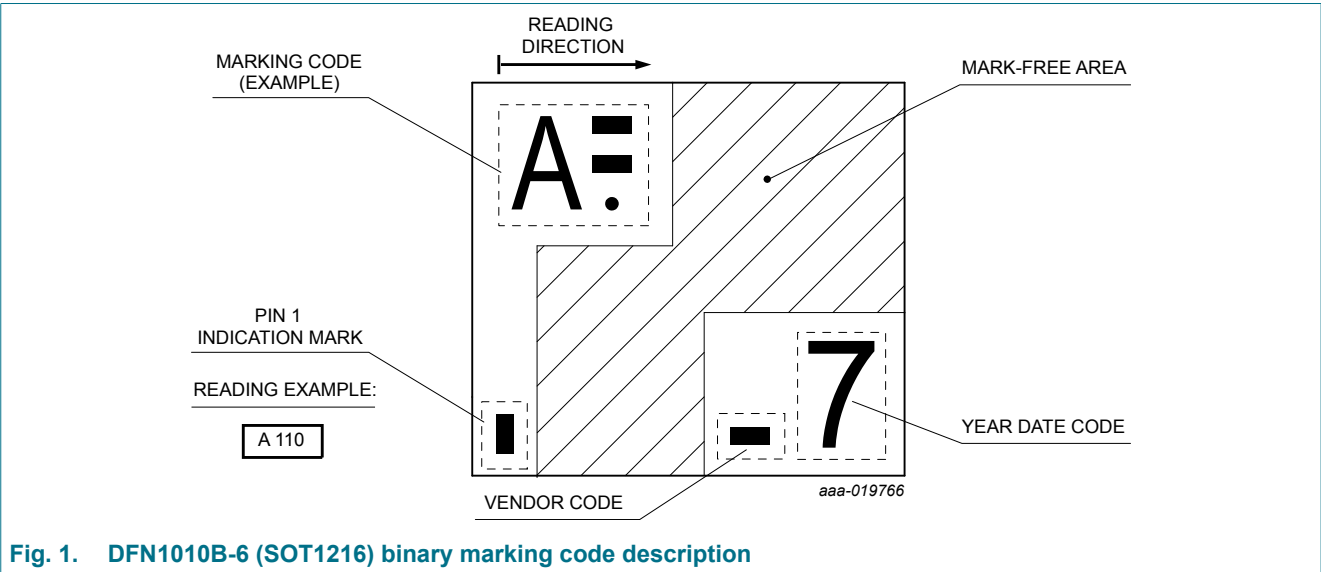
Table 3. Ordering information

Type number	Package		
	Name	Description	Version
BCM857QAS	DFN1010B-6	DFN1010B-6: plastic thermal enhanced ultra thin small outline package; no leads; 6 terminals	SOT1216

7. Marking

Table 4. Marking codes

Type number	Marking code
BCM857QAS	C 011

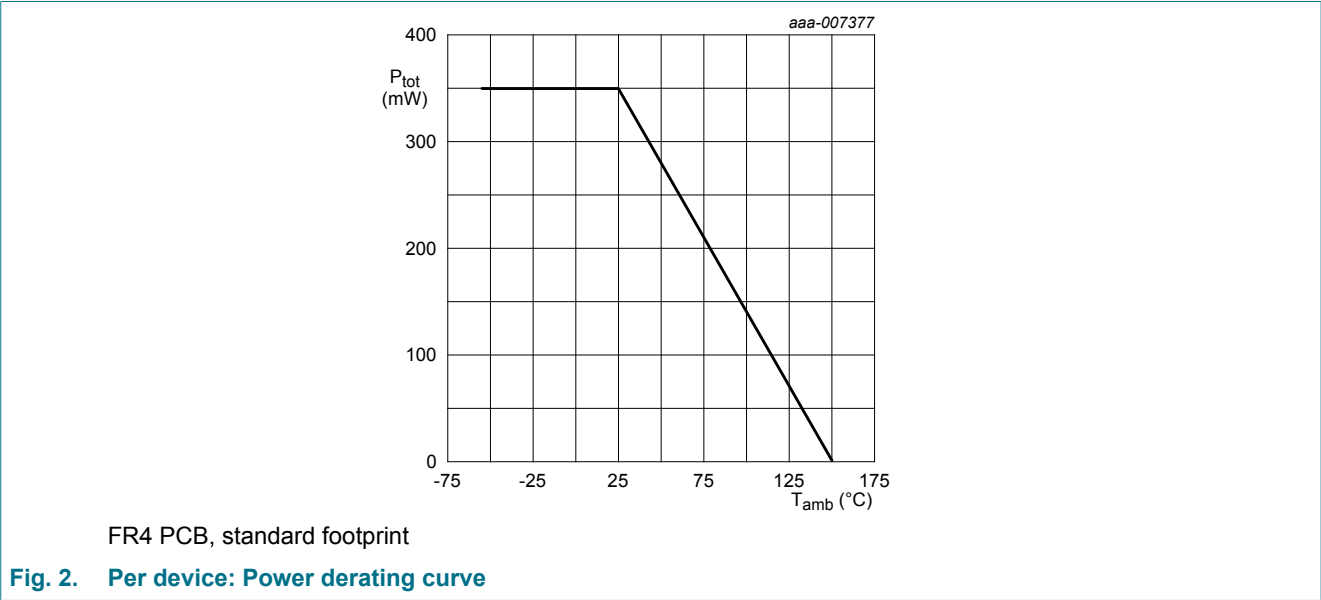


8. Limiting values

Table 5. Limiting values
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
Per transistor						
V _{CBO}	collector-base voltage	open emitter		-	-50	V
V _{CEO}	collector-emitter voltage	open base		-	-45	V
V _{EBO}	emitter-base voltage	open collector		-	-6	V
I _C	collector current			-	-100	mA
I _{CM}	peak collector current	t _p ≤ 1 ms; single pulse		-	-200	mA
I _{BM}	peak base current			-	-100	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	230	mW
Per device						
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	350	mW
T _j	junction temperature			-	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

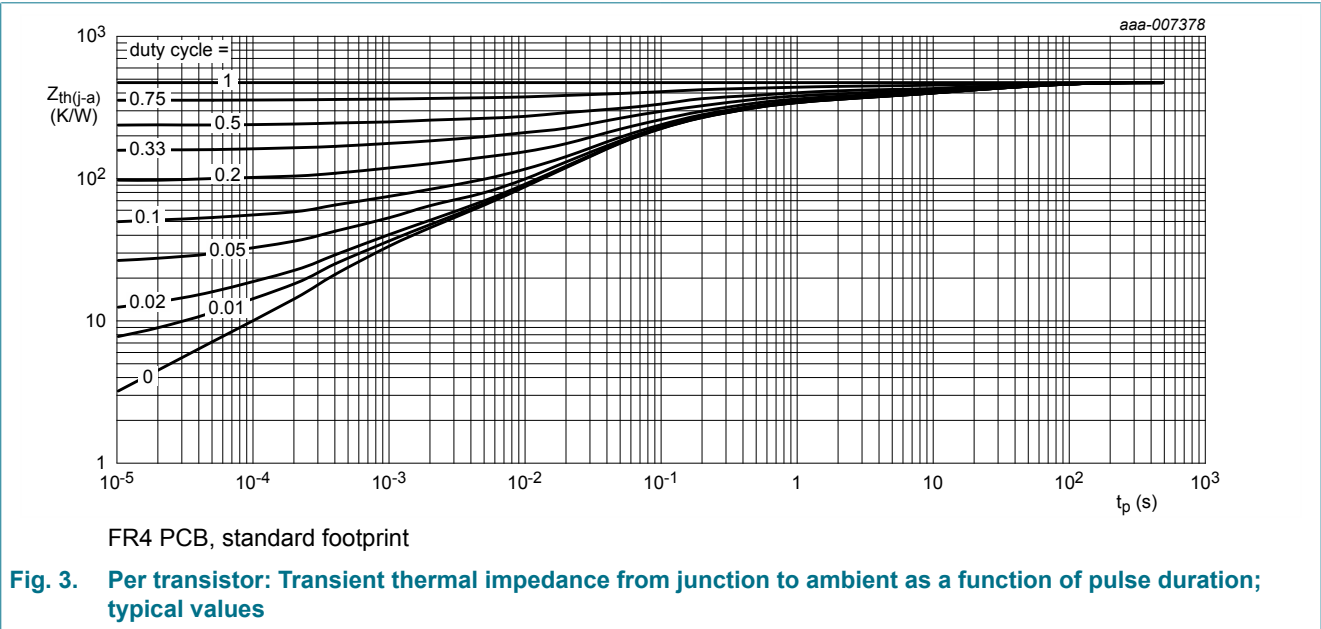


9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
Per transistor							
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	544	K/W
Per device							
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	358	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.



10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
Per transistor							
$V_{(BR)CBO}$	collector-base breakdown voltage	$I_C = -100\ \mu\text{A}$; $I_E = 0\ \text{A}$		-50	-	-	V
$V_{(BR)CEO}$	collector-emitter breakdown voltage	$I_C = -2\ \text{mA}$; $I_B = 0\ \text{A}$		-45	-	-	V
$V_{(BR)EBO}$	emitter-base breakdown voltage	$I_C = 0\ \text{A}$; $I_E = -100\ \mu\text{A}$		-6	-	-	V
I_{CBO}	collector-base cut-off current	$V_{CB} = -30\ \text{V}$; $I_E = 0\ \text{A}$; $T_{amb} = 25\ ^\circ\text{C}$		-	-	-15	nA
		$V_{CB} = -30\ \text{V}$; $I_E = 0\ \text{A}$; $T_j = 150\ ^\circ\text{C}$		-	-	-5	μA
I_{EBO}	emitter-base cut-off current	$V_{EB} = -5\ \text{V}$; $I_C = 0\ \text{A}$; $T_{amb} = 25\ ^\circ\text{C}$		-	-	-100	nA
h_{FE}	DC current gain	$V_{CE} = -5\ \text{V}$; $I_C = -10\ \mu\text{A}$; $T_{amb} = 25\ ^\circ\text{C}$		-	250	-	
		$V_{CE} = -5\ \text{V}$; $I_C = -2\ \text{mA}$; $T_{amb} = 25\ ^\circ\text{C}$		200	290	450	
V_{CEsat}	collector-emitter saturation voltage	$I_C = -10\ \text{mA}$; $I_B = -0.5\ \text{mA}$; $T_{amb} = 25\ ^\circ\text{C}$		-	-	-200	mV
		$I_C = -100\ \text{mA}$; $I_B = -5\ \text{mA}$; $T_{amb} = 25\ ^\circ\text{C}$ [1]		-	-	-400	mV
V_{BEsat}	base-emitter saturation voltage	$I_C = -10\ \text{mA}$; $I_B = -0.5\ \text{mA}$; $T_{amb} = 25\ ^\circ\text{C}$ [2]		-	-760	-	mV
		$I_C = -100\ \text{mA}$; $I_B = -5\ \text{mA}$; $T_{amb} = 25\ ^\circ\text{C}$ [2]		-	-900	-	mV
V_{BE}	base-emitter voltage	$V_{CE} = -5\ \text{V}$; $I_C = -2\ \text{mA}$; $T_{amb} = 25\ ^\circ\text{C}$ [3]		-600	-660	-725	mV
		$V_{CE} = -5\ \text{V}$; $I_C = -10\ \text{mA}$; $T_{amb} = 25\ ^\circ\text{C}$ [3]		-	-710	-820	mV
C_c	collector capacitance	$V_{CB} = -10\ \text{V}$; $I_E = 0\ \text{A}$; $i_e = 0\ \text{A}$; $f = 1\ \text{MHz}$; $T_{amb} = 25\ ^\circ\text{C}$		-	-	4	pF
C_e	emitter capacitance	$V_{EB} = -0.5\ \text{V}$; $I_C = 0\ \text{A}$; $f = 1\ \text{MHz}$; $T_{amb} = 25\ ^\circ\text{C}$		-	10	-	pF
f_T	transition frequency	$V_{CE} = -5\ \text{V}$; $I_C = -10\ \text{mA}$; $f = 100\ \text{MHz}$; $T_{amb} = 25\ ^\circ\text{C}$		100	175	-	MHz
Per device							
h_{FE1}/h_{FE2}	DC current gain matching	$V_{CE} = -5\ \text{V}$; $I_C = -2\ \text{mA}$; $T_{amb} = 25\ ^\circ\text{C}$		0.95	1	1.05	
$V_{BE1}-V_{BE2}$	base-emitter voltage matching		[4]	-	-	2	mV

[1] Pulse test: $t_p \leq 300\ \mu\text{s}$; $\delta \leq 0.02$

[2] V_{BEsat} decreases by about $1.7\ \text{mV/K}$ with increasing temperature.

[3] V_{BE} decreases by about $2\ \text{mV/K}$ with increasing temperature.

[4] The smaller of the two values is subtracted from the larger value.

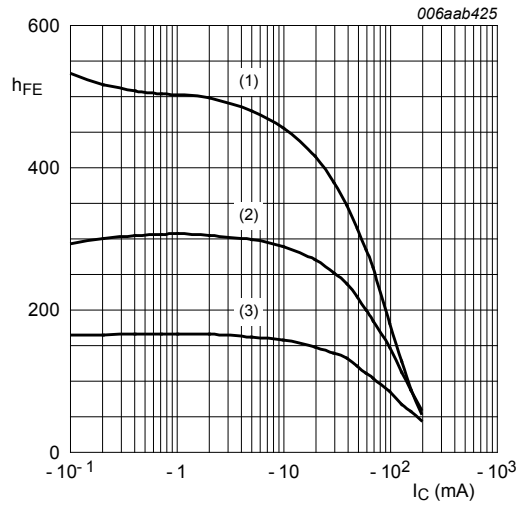


Fig. 4. DC current gain as a function of collector current; typical values

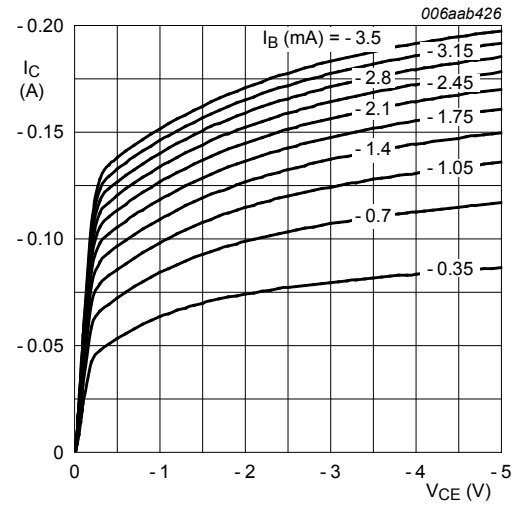


Fig. 5. Collector current as a function of collector-emitter voltage; typical values

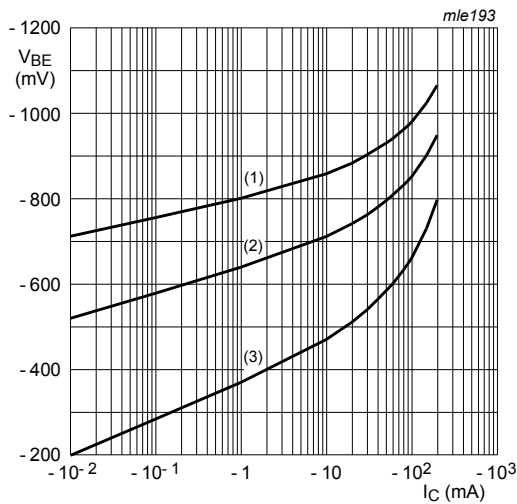


Fig. 6. Base-emitter voltage as a function of collector current; typical values

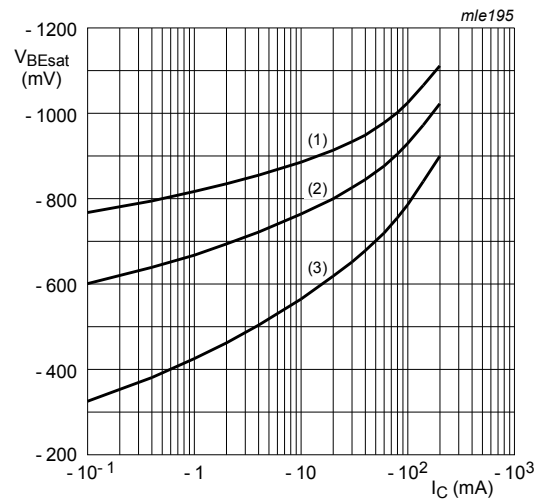


Fig. 7. Base-emitter saturation voltage as a function of collector current; typical values

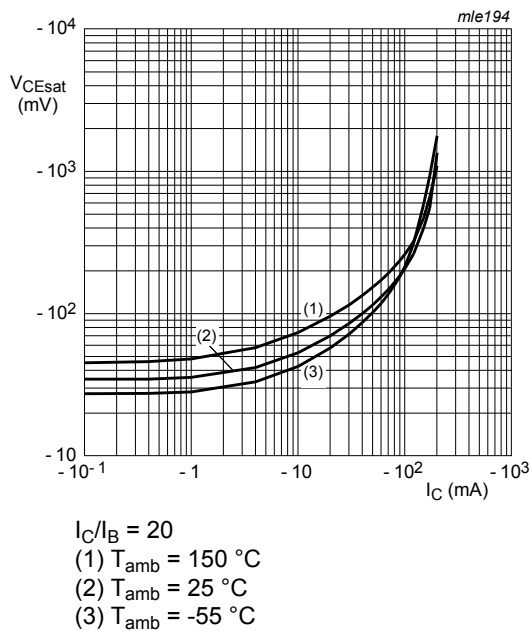


Fig. 8. Collector-emitter saturation voltage as a function of collector current; typical values

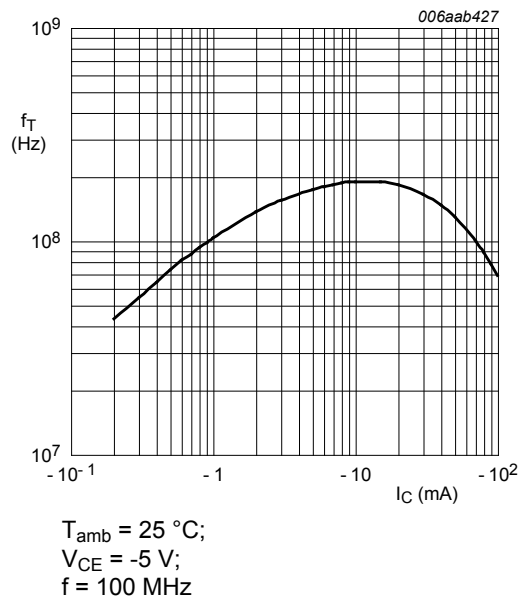


Fig. 9. Transition frequency as a function of collector current; typical values

11. Test information

Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

12. Package outline

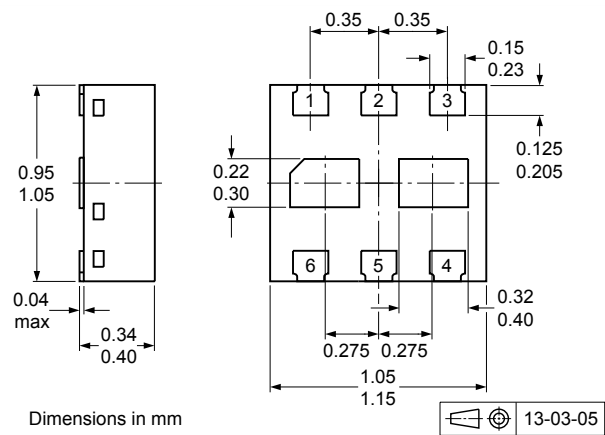


Fig. 10. Package outline DFN1010B-6 (SOT1216)

14. Revision history

Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
BCM857QAS v.1	20180424	Product data sheet	-	-

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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Date of release: 24 April 2018

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